Param agnetic reentrance of the ac-screening: Evidence of vortex avalanches in Pb thin lm s

A.V. Silhanek, S. Raedts, and V.V. Moshchalkov

Nanoscale Superconductivity and Magnetism Group, Laboratory for Solid State Physics and Magnetism K.U.Leuven Celestijnenkan 200 D, B-3001 Leuven, Belgium

(D ated: M arch 22, 2024)

We have studied the in uence of a square array of pinning centers on the dynamics of vortex avalanches in Pb thin lm s by m eans of ac- and dc- m agnetization m easurem ents. C lose to the superconducting transition T_c the commensurability between the vortex lattice and the pinning array leads to the well known local increments of the critical current. As tem perature T decreases, m atching features progressively fade out and eventually disappear. Further down in temperature vortex avalanches develop and dom inate the magnetic response. These avalanches manifest them selves as jumps in the dc-m agnetization and produce a lower ac-shielding giving rise to a param agnetic reentrance in the ac-screening $^{0}(T)$. Within the ux jump regime two subregimes can be identied. C lose to the boundary where vortex avalanches develope, the eld separation between consecutive jumps follow the periodicity of the pinning array and a eld and temperature dependent screening is observed. In this regime, the response also depends on frequency f in agreement with theoretical m odels for m agnetotherm al instabilities. At low enough tem peratures and elds, the screening saturates to a constant value independent of T, H, and f, where jum ps are random ly distributed. We have also found that vortex instabilities occupy a larger portion of the H T diagram in patterned samples than in lm swithout nanoengineered pinning sites. Finally, we discuss the possible origin of the vortex avalanches and com pare our results with previous experim ental and theoretical studies.

I. IN TRODUCTION

If a type-II superconductor is cooled down in a zero applied eld (ZFC experiment) and subsequently an external eld H larger than the rst critical eld H_1 is applied, ux-bearing vortices enter through the sam ple's borders until they are captured by pinning centers. As a consequence, the system achieves an inhom ogeneous ux distribution with a higher density of vortices near the borders that progressively decreases tow and the center of the sam ple. The spatial variation of the locally averaged

eld B (r) gives rise to supercurrents J in the sam ple that, in the stationary state, accommodate to be exactly the critical current J_c everywhere. The resultant inhomogeneous ux distribution of this so-called critical state, represents a self organized state that under small perturbations (like local temperature uctuations T) can lead to vortex avalanches in order to maintain $J = J_c$ (H;T) in that region. Because of the dissipation produced when

ux lines m ove, each avalanche gives rise to a heat pulse and therefore a local increment of the temperature $T_{\rm f}$. If $T_{\rm f} < T_{\rm i}$ the critical state remains stable under these perturbations, otherwise avalanches of vortices draw the sample to a highly resistive state.¹

The way in which the vortex lattice reacts to the local overheating is crucial to determ ine the subsequent dynam ics of the system . If the di usivity of the magnetic

ux (given by the resistivity) is sm aller than the therm aldi usion coe cient (given by =C, where the heat conductivity and C is the heat capacity), the hot spot propagates in a frozen m agnetic and current distribution (dynam ic approxim ation). On the other hand, if therm aldi usivity is sm aller than m agnetic di usivity there is not enough time to remove or distribute the heat produced by the vortex motion (adiabatic heating).² In both cases, the stability criterion for the critical state reads,

$$\frac{s^2}{J_c} J_c \frac{dJ_c}{dT} < 1; \qquad (1)$$

where s is the characteristic sample dimension, $= C = _0$ in the adiabatic approximation and = = in the dynamic approximation²

A thigh tem peratures and elds, where the critical current is small, vortex avalanches are usually not seen. As tem perature and eld decrease, critical current increases and below a certain boundary H (T) vortex avalanches develop. In principle this scenario should apply with m inor di erences for both bulk sam ples and thin lm s. However, recent m agneto-optical im ages (MO)

have shown that in thin Im s, with H applied perpendicular to the plane of the Im, the ux pattern in the sam ple exhibits a richer morphology than the smooth progressive ux penetration observed in the bulk. For this particular geometry, ux invasion occurs via dendritic structures which cover a substantial portion of the sam ple's area and grow very fast (i.e. under adiabatic conditions).³ The therm all origin of the observed instabilities has been recently demonstrated by strongly suppressing the dendrite instabilities as the therm all contact is im proved.⁴

Typically, the observed sudden penetrations of the ux front into the sample are accompanied by sharp jumps in the dc-m agnetization.^{1,5,6,7} T hese jumps generate a noisy response which can underm ine the technological applicability and perspectives of superconducting devices at low

tem peratures. However, recent prom ising experimental results have shown that this noise can be substantially reduced by introducing an array of pinning centers,^{8,9,10} at expenses of increasing considerably the region in the H T diagram where ux jumps occur¹¹.

A dditionally, in a recent work, A ranson et al.¹² have theoretically predicted that the presence of a periodic m odulation of the critical current would give rise to a growth of the branching process of the dendrites in com – parison with a hom ogeneous pinning distribution. E vidence supporting this picture was reported by V lasko-V lasov et al.¹³ who analyzed the M O im ages of N b Im s patterned with a square lattice of holes. The authors show that as the eld is progressively ram ped up, rst the ux enters from the edges in stripes with boundaries along the principal axes of the pinning array and then new stripes jump between previously developed stripes. The width of these stripes involves several units cell of the pinning array.

On top of that, magnetization measurements performed on Nb¹⁴ and Pb¹¹ In s with a square array of holes show that the eld separation between consecutive jumps commensurate with the period of the underlying pinning array. This is a surprising result since matching features are typically seen only very close to T_c where intrinsic pinning and self- eld e ects are not relevant. C learly, the in uence of the vortex pinning in the morphology and dynamics of the ux penetration on these kind of systems is an issue that has not been fully addressed so far and deserves further investigations.

In this work we study the ux-jump regime in Pb thin Im s with and without periodic pinning by means of acand dc-susceptibility measurements. In the sam ples with a square antidot array several regimes can be identified as a function of temperature. For temperatures T T_c, m atching features appear when the vortex lattice com mensurates with the pinning array. As temperature decreases these e ects progressively fade out. At a certain

eld-dependent tem perature the shielding power of the sam ple is dram atically reduced and a reentrance in the ac-screening $^{0}(\Gamma)$ is observed. This e ect is accompanied by a substantial increase of the dissipation 00 . We demonstrate that the observed reentrance is related to the appearance of ux jumps in the sam ple. Finally we discuss the origin of the quasi-periodic jumps in terms of a multiterrace critical state.

II. EXPERIMENTAL DETAILS

The experiments were conducted on Pb thin Im swith dierent pinning arrays. The dimensions and critical temperature for each sample are summarized in Table I. In all patterned samples the square antidot array consists of square pinning sites with lateral dimension b = 0.8 m and period d = 1.5 m which corresponds to a rst matching eld $H_1 = 9.2$ G. Simultaneously with each patterned Im we deposited a plain reference Im on SiD_2 substrate which allows us to perform a direct and reliable comparison in order to discrim inate the e ects of the pinning array. From the temperature dependence of the upper critical eld H_{c2} (T) we have estimated a superconducting coherence length (0) = 33 3 nm for all samples.

TABLE I:Lateraldim ensions (w₁ and w₂), thickness (t), and criticaltem peratures (T_c) for all the lm s studied. AD stem s from square array of antidots and BH from square array of blind holes.

Sam ple w	1 (mm) v	v ₂ (mm)	t (nm)	$T_{\rm c}$ (K)
AD 15	1.9	2.0	13.5	7.10
AD 65	2.3	2.5	65	7.21
BH100	3.2	3.3	100	7.22

The details of the sample preparation can be found in Ref.[15]. Brie y, the prede ned resistdot patterns were prepared by electron-beam lithography in a polymethyl metacrylate/methyl metacrylate (PMMA/MMA) resist bilayer covering the SiO₂ substrate. A Ge(20 A)/Pb/Ge(200 A) Im was then electron-beam evaporated onto this mask while keeping the substrate at liquid nitrogen temperature. Finally, the resist was removed in a lift-o procedure in warm acetone. The BH100 blind hole array was fabricated by depositing an additional25 nm -thick Pb Im on top of a 75 nm -thick Pb Im with an array of antidots.

The ac-susceptibility m easurements (H;T) = 0 + i 00 were carried out in a commercialQ uantum Design-PPMS device with drive eld amplitudes h ranging from 2 m O e to 10 O e, and the frequency f from 10 Hz to 15 kHz. The data were normalized to have a total step 0 = 1, with H = 0 at low temperatures and ac drives. This system provides a temperature stability better than 0.5 mK which is crucial for m easurements near the critical temperature. The dc-magnetization m easurements were obtained using a QD -M PM S SQUID m agnetometer equipped with a 5 T m agnet.

III. RESULTSAND DISCUSSION

A. D c-m agnetization

In order to identify the tem perature range where ux jumps occur, we have measured zero eld cooled (ZFC) and eld-cooled (FC) dc-magnetization for a xed eld H. The result of these measurements is shown in the main panel of Fig. 1 for the AD 15 sample at H = 5 G. A reversible response is obtained for T_c T < 0.7 K, a tem perature range higher than the expected for the irreversible line at this eld,¹⁶ probably due to the presence of an undesirable remanent eld in the initial cooling procedure.

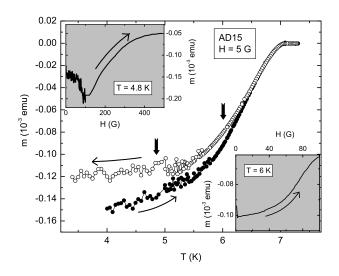


FIG. 1: Main panel: Zero-eld cooling (led circles) and eld-cooling (open circles) dc-m agnetization as a function of temperature for the AD15 sample at H = 5 G. The vertical black arrows indicate the temperature where the loops shown in the insets where recorded.

The AD 15 sample is the same as that used in our previous studies.¹⁷ In that work we show that commensurability e ects between the ux line lattice and the pinning array manifest them selves as a peak in the critical current or as a higher screening in the ac-response. In this particular sample, well de ned matching features appear only forT_c 0:6 K. For low er tem peratures (T < 6:5 K), Т the decrease of the penetration depth (T), the grow th of the intrinsic pinning strength and self-eld e ects⁸ lead to a less pronounced m atching features, which eventually disappear. Decreasing further the tem perature there is a clear transition to a regim e w here m agnetization becom es notably noisy. This transition occurs for both ZFC and FC curves around T = 5.7 K indicating that the onset of the crossover to a sm ooth behavior at high tem peratures is highly reproducible. O fcourse the noisy response 0:1m) is not related to the experim ental resolution (m of the used device since in this regime the signal/noise ratio is higher than near T_c where a sm ooth curve is obtained. Instead, we argue that at T = 5.7 K a transition to a more dissipative state owing to ux jumps takes place. Evidence corroborating this interpretation is obtained by measuring hysteresis loops at T = 4.8 K deep in the noisy regime (upper inset of Fig. 1) and at T = 6K where the noise is absent (low er inset of Fig. 1). It can be seen that at T = 6 K jumps in the dc-m agnetization never occur. In contrast to that, at T = 4.8 Kux jum ps are present in the low eld region up to 100 G, where the average magnetization reaches a maximum. For H > 100 G, the irreversible m agnetization decreases smoothly as eld increases in agreement with a critical state scenario. As it has been pointed out previously,

the magnetization peak at 100 G indicates the onset of vortex avalanches in the sample. 6

B. A c-susceptibility

The appearance of ux-jumps should also be relected as a lower electer to screen out an external acled. This elect can be seen in the lower panel of Figure 2 where the screening ⁰ and the dissipation ⁰⁰ as a function of temperature are shown for the AD15 sample at H = 5 G and several acle excitations.

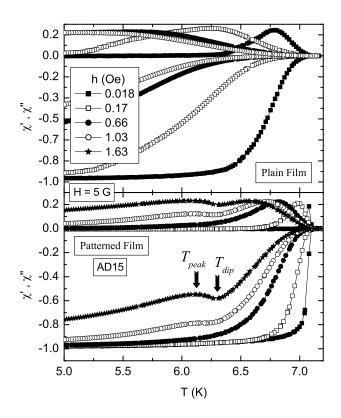


FIG.2: Tem perature dependence of the ac-susceptibility = 0 + i $^{\infty}$ at several ac-drives h for a plain lm (upper panel) and a lm with a square array of holes (lower panel). In the lower panel the transition to a ux-jum ps regime appears as a reentrance signaled by the features $T_{\rm dip}$ and $T_{\rm peak}$ (see arrow s).

At low ac drives no features indicating the transition to a ux-jum ps regime are observed. For h 1G a param agnetic reentrance in the screening at T 6:3K signals the onset of ux-jumps regime. It should be noted that the ac drive at which the reentrance in $^{0}(T)$ rst ap-1 G, is the sam e order as the average distance pears, h between the jumps H i 3 G. This result suggests that H j new vortex avalanches are not trigas long as h gered and the transition to the ux jumps regime is not detectable. Consistently, we have observed a weak in uence of the amplitude h on the position where jum ps rst

develop. This is shown in the inset of Figure 3 where we can see that at low amplitudes, both the localm inimum T_{dip} and the localm aximum T_{peak} , remain almost constant as h increases. From h = 4 G up, the transition temperature slowly decreases with increasing h. As we will show below this e ect is a consequence of a T_{dip} decreasing with increasing the total eld H + h. There is a system atic sm all discrepancy between the onset of the ux-jum ps regime determined by dc-m agnetization and

ac-susceptibility. This e ect can be attributed to a faster onset of vortex avalanches due to the ac shaking.

It is worth to note that the tem perature evolution of the curves at tem peratures above T_{dip} and below T_{peak} follows a quite di erent trend. Sim ilar behavior has been recently reported by Passos et al.¹⁹ for M gB₂ sam ples and attributed to a possible eld induced granularity. The origin of the reentrant behavior in the screening can be understood from the upper inset of Fig. 1. In this gure we can see that the developm ent of avalanches leads to a reduction of the average critical current and therefore also to a reduction in the screening properties. In other words, when the system crosses from a \non-jum py" regime to a \jumpy" regime, either by sweeping eld or tem perature, a strong suppression of the screening power occurs. A sa rule, every peak in the dc-m agnetization (either in eld or tem perature) will manifest itself as a dip in the ac-screening.^{20,21}

For comparison, in the upper panel of Figure 2 we show similar measurements performed on a plain lm (without nanoengineered pinning array) for the same ac drives and dc eld. In the window oftem peratures shown here, no features indicating the ux-jump transition are found. How ever, a reentrance appears at $T_{\rm dip}$ 3.8 K for $H = 5 \, \text{G}$. This reduction of $T_{\rm dip}$ in the unpatterned sam – ple is in agreement with recent magnetization measurements performed in sam ples with and without a periodic pinning array.¹¹

It should be noted that perform ing ac-susceptibility m easurements the \noise" produced by the ux jumps is removed. This is so because the measurements here presented were obtained at a relatively high frequency f = 3837 Hz and with an integration time of 1 sec, therefore the resultant reject an average after cycling 3837 times a minor bop. By reducing the number of cycles one may approach to the case of dc-magnetization measurements and jumps become more apparent.

The transition to the ux-jump regime becomes more obvious by plotting the in aginary versus the realpart of the ac-susceptibility: ⁰⁰ ⁰ as shown in the main panel of Fig. 3. The advantages of this so-called C ole-C ole plot is two fold, rst it makes possible a comparison among di errent samples without knowing the speci c value of the critical current,²² secondly it allows one to identify clearly di errent vortex dynamics regimes. In Figure 3 we show this representation with obtained by sweeping tem perature at several h (part of these data were already shown in Figure 2). All these curves show a similar general behavior. Starting from high tem peratures (right

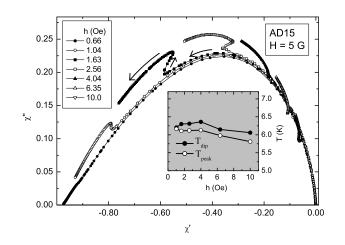


FIG.3: Main panel: 00 vs 0 obtained from (T) curves at several ac-am plitudes h for the AD 15 sam ple (som e of these curves are shown in the lower panel of Figure 2). The sm all arrows indicate the evolution of the curve as T decreases. The inset shows the transition temperatures T_{dip} and T_{peak} (see Figure 2) as a function of h.

side) we rst observe an increase in both dissipation and screening as T decreases, until the transition tem perature T_{dip} is reached, then a sudden reduction of the screening together with an increase of the dissipation occurs down to T_{peak}. Below this tem perature, the curves continue with a sm ooth evolution. Rem arkably, the whole fam ily of curves m erges in two well distinguished evolvents, one for $T > T_{dip}$ and the other for $T < T_{peak}$, the latter being m ore dissipative than the form er. A dditionally, the peak of maximum dissipation is shifted from 0 0:365 for $T > T_{dip}$ to ⁰ 0:408 for T < Teak . This increase in magnitude of the maximum 00 together with the shift tow ards $^{0} =$ 1 is commonly observed in high tem perature superconductors and attributed to creep e ects. A s we will discuss below the higher dissipative state is accompanied by a f-dependence susceptibility analogous to a creep regime where the frequency dependence of the magnetic response appears as a consequence of the dynam ic evolution of the system (not considered in a conventional critical state m odel).

Once we have identi ed the temperature T_{dip} (or T_{peak}) as the transition temperature to a ux-jmps regime, we can determ ine the portion of the H T diagram where these instabilities dom inate by tracking the dip position as a function of the dc ed. Some of these curves are shown in the main panel of Figure 4 for the AD 65 sample at h = 3 G. In this gure it can be seen that the transition T_{dip} shifts to lower temperatures as H increases. This result is a consequence of a critical current J_c decreasing with increasing H and in agreement with previous experimental reports.¹¹ It is also interesting to notice that at low temperatures and edds all these curves merge into a single universal behavior.

This eld independent curve indicates that the average inveversible magnetization in this region is also eld independent. This is con m ed by the dcm agnetization m easurements shown in the main panel of Figure 6 for the BH 100 sample and by recent experiments performed on plain Pb $\mathrm{Im\ s^{23}}$ A nother important observation is that at low temperatures the universal magnetization seems to saturate to a value 0 0:91, and hence it also becomes temperature independent. O f course, at higher

elds (H > 100 G) this eld independent behavior is progressively lost as the system approaches the boundary H (T).

This striking T - and H -independent average m agnetization at low temperatures m ight be attributed to the coexistence of two di erent species of vortices. Indeed, it has been shown that in this regime dendrites have a

nger-like structure with a size which remains unaltered with further changing the eld. This very stable pattern of ux penetrated regions is a consequence of the tendency of dendrites to avoid each other. Once the eld is reduced, already developed dendrites may help to remove ux from the sample and also channel incoming vortices when the eld is again increased. In this picture, the ac response would be dominated by the easy motion of vortices inside the dendrites thus leading to a lower saturation value 0 0:91.

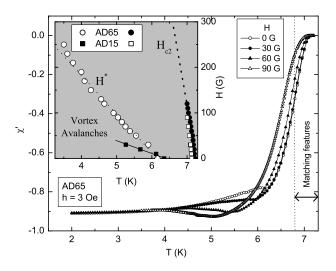


FIG. 4: Main panel: $^{0}(T)$ for the AD 65 sample at h = 3 G and several elds. The vertical dashed line indicates the lowest temperature where m atching features are still barely de ned. The inset shows the di erent observed regimes in a H T phase diagram for the AD 15 (square symbols) and AD 65 (circle symbols) samples. The boundary H (T) represents the position of the local minimum in the $^{0}(T)$ curves shown in the main panel.

In the inset of F ig. 4 we show the resultant phase diagram obtained following the procedure described above for the AD 65 (open circles) and AD 15 (led squares) samples together with the upper critical eld H_{c2} (T) for

both sam ples.24 An alm ost linear tem perature dependence of the boundary H_{dip} (T) is observed in the whole range of tem peratures. Note that the observed di erent slopes of the boundary H (T) (a factor of 3 steeper for the AD 65 sam ple) cannot be ascribed to a di erent tem perature dependence of H c2 since the upper critical eld is roughly sample independent. As a consequence, the Η T region of ux-instabilities for the AD 15 turns out to be sm aller than for the AD 65 sam ple. This reduction of the ux-instability region with decreasing the lm's thickness is in agreement with previous observations in Nb thin lm s⁶. Indeed, if H is applied perpendicular to the sam ple's surface, the e ective size s which determ ines the stability criterion in eq.(1) can be approximated as wt=2, where w is the width of the $lm \cdot 6^{25}$ Uss ing the sample dimensions shown in Table I we obtain s = 3 m and s = 8 m for the AD15 and AD65 sam ples, respectively. From eq.(1) we have that for dim ensions s such that $s^2 > \ s^2_{\text{crit}} = \ \frac{1}{J_2} \ \frac{dJ_c^2}{dT}$ jvortex instabilities appear. In other words, the sm aller the s the lower the boundary H (T), in agreem ent with our observation.

As we pointed out previously, the transition to the vortex-instability regimemanifests itself as a peak in the dcm agnetization loops such as that shown in the upper inset of Fig.1. Similarly, we can determ ine this transition

eld by perform ing $^{0}(H)$ measurem ents at several tem peratures as is shown in the inset of Fig. 5 for the AD 65 sample. In this gure, the data recorded at T = 6.5 Kfall, for all elds, in the stable regime where no jumps are observed and therefore exhibits the standard maximum screening at zero eld. For the rest of the explored temperatures T < 6 K the maximum screening is no longer located at zero eld but at H_{peak} which roughly coincides with the boundary H (T) shown in the inset of Fig. 4. We observe that at low temperatures a plateau in $^{0}(H)$ appears around H = 0 in agreement with our previous remark. This constancy of ⁰(H) im plies a xed size of the ux avalanches and a eld and tem perature independent m agnetization. This is consistent with recently reported avalanche distribution perform ed in sim ilar sam ples¹¹ and m agnetization m easurem ents on plain Pb $\ln s^{23}$. According to Ref.[11], for T < 5 K the size distribution of ux-jumps does not depend strongly on temperature and in particular, the maximum jump remains almost constant. This e ect is not inherent of samples with a periodic pinning array since similar results were found in unpatterned Pb Im s.²³ At lower tem peratures (T < 3 K) a peak in 0 (H) around H = 0 reappears although its maximum screening at H = 0 is always smaller than $^{0} =$ 0:91. So, still this saturation value in poses an upper bound for the maximum possible screening in the ux-jump regime.

Lets now discuss what kind of instability corresponds to the observed behavior. An estimation of the ratio = =C between thermal and magnetic di usivities, using^{26,27} C = 0:67 J/K g-K and = 3:4 W /cm -K, and considering that $_{\rm ff}$ where $_{\rm ff}$ = $_{\rm n}$ H =H $_{\rm c2}$ is the ux- ow resistivity and $_{\rm n}$ 0:02 m the normal state

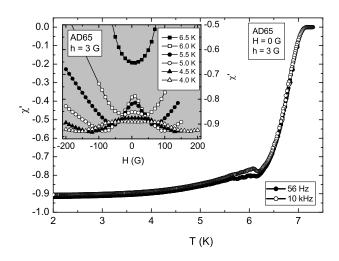


FIG.5: M ain panel: 0 (T) for the AD 65 sam ple at zero eld, h = 3 G and two extreme frequencies. The inset shows the eld dependence of the screening 0 for several tem peratures. At low T and H, the ux-jump regime manifests itself as a reduction of the screening.

resistivity, gives 1 at 4 K and H = 100 G .Therefore, within this context neither the adiabatic nor the dynam ic (or isotherm al) approxim ations seem s to be appropriate. However, in the estim ate we made several im portant points are not included. First, the heat rem oval through the substrate which results in a lower local increase of the tem perature.⁴ Second, the eld and tem perature dependence of the speci c heat and the therm al conductivity. All these e ects tend to reduce the value of the e ective thus approaching to the adiabatic lim it. In addition, our estim ate is based on a critical state m odel where the dendritic penetration observed in these sam ples is not considered.¹³ M oreover, it is in portant to note that ux jum ps are not mounted on a continuous prolongation of the curve observed at high eld (see Fig.6), thus suggesting that the observed vortex avalanches cannot be described within a critical state scenario. It is believed that in thin Im s the long-range vortex-vortex interaction and the non-local current- eld relation are key ingredients which should eventually be incorporated in order to describe the branching process of the ux penetration 3,28

On the other hand, the similarity between the measurements presented in this work and those previously reported in several other materials (M gB₂, ⁷ Nb, ^{5,13} Pb, ²³ Nb₃Sn²⁹) points to magnetothermal instabilities as the origin of the ux jumps at low temperatures. A swem entioned in the Introduction, there is a rich zoology of possible vortex avalanches like smooth ux fronts, nger-like penetration or highly-branched tree-like ux invasion. In M gB₂, M O in ages indicate that quasi-unidimensional ngers occur at low temperatures whereas at intermediate temperatures a branched structure dominates.⁷ Sim ilarly, V lasko-V lasov et al.¹³ show ed that in Nb Im spattermed with an array of holes ux penetrates as stripes at low elds (resembling the ngers observed in MgB₂) whereas at higher elds a branching process produced by \mbox{m} agnetic discharging" connects the original stripes. This fast ux penetration strongly suggests that our results can be described within the adiabatic approximation.

Another interesting result com es from the analysis of the frequency dependence of the screening. According to the commonly used theoreticalm odels, in both lim its, dvnam ic (1) and adiabatic (1), the size and the distance between jumps should decrease with increasing the eld sweep rate $dH = dt^{2,30}$ It has been also experimentally show n³⁰ that the mean value of the magnetization, which is in fact what we are able to determ ine with ac-susceptibility, decreases with increasing dH =dt. In order to study this e ect we have measured the $^{0}(T)$ at h = 3 G for two extrem e frequencies f = 56 H z and f = 10 kHz, as shown in the main panel of Fig. 5. This frequencies correspond to a eld sweeping rate of 0:05 T/s an 12 T/s, respectively, thus widely covering the range where f-dependence has been observed in other materials.³⁰ Surprisingly, there is almost no frequency dependence un less in a narrow tem perature window right below T_{dip} where a sm aller screening is detected for the higher frequency as expected.³⁰ On the other hand, the lack of dH = dt dependence in the low tem perature regim e has been also reported in Ref.[6,11] although in these publications the used dH =dt covered a much smaller range.

C. In uence of the periodic pinning

W e now turn to the analysis of a possible m atching between the periodicity of the jumps and that imposed by the pinning landscape. It has been recently shown, rst by Terentiev et al.¹⁴ in Nb Im s and later on by H ebert et al.¹¹ in Pb Imsthat within the ux-jump regime and at high enough tem peratures and elds, the distance between consecutive jum ps H i coincides with a multiple of the matching eld nH1, with n integer. We have conmed that this e ect seems to be also present in the BH100 sample. Indeed, the upper right inset of Fig. 6 shows a zoom - in of the decreasing branch in the uxjumps region for the BH100 sample at T = 5.25 K. A Fourier spectrum analysis of these data shows that there are three maxim a corresponding to H $_{1}$ = 12.8 G, 9.9 G and 4.3 G which are relatively close to the matching conditions H_j=H₁ = 1.5, 1 and 1/2, respectively. A pparently these periodic jum ps appear close to the boundary H (T) with a jump size larger than that observed at lower tem peratures and elds.

These a priori unexpected commensurability elects at low temperatures represent a striking observation since just above the transition $T_{\rm dip}\left(H\right.$) there are no special features indicating the commensurability elects. The absence of matching features above $T_{\rm dip}\left(H\right.$) is an indication

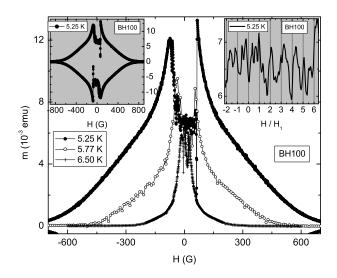


FIG.6: The main panel shows the decreasing branches of dcmagnetization boops recorded at three di erent temperatures for the BH100 sample. In the ux-jumps regime the average magnetization tends to a common value. A full hysteresys boop is shown in the left inset. The right inset shows a zoom in of the ux jump regime where quasi-periodic jumps appear. The units used in the vertical axes of the insets is the same as the one used in the main panel.

that vortices are no longer regularly distributed. However, the in uence of the periodic pinning array might still play an inportant role as it favors an easier motion of vortices along the rows of the array than at any other orientation.³¹ This picture is consistent with the M O m easurements of R ef.[13] showing preferential penetration along the principal axes of the pinning array. Moreover, recent M O im ages³² performed on YBa₂Cu₃O_{7 x} thin ln s with a square array of holes at very low tem peratures (T = 4.5 K) where no matching e ects are observed, showed that the penetration of the ux front is highly anisotropic as a consequence of a strong guidance of vortices by the underlying pinning structure.

Currently it is still a puzzling question why the period of the jumps coincides with multiples of H_1 . In R ef.[14] the authors postulate that at low tem peratures, regular vortex structures may appear in a ux depleted region near the border of the sam ple as a result of geom etric barriers (GB). As eld is increased, this vortex-poor contour region is progressively lled with vortices which form a highly stable vortex pattern sim ilar to those normally observed close to T_c . Above a certain threshold (i.e. $H_J = nH_1$) the vortex distribution in the border becomes unstable and is pushed towards the center of the sam ple by the screening currents thus triggering a ux avalanche. A rst step in order to elucidate the origin of the observed quasi-periodic jumps is to discem whether GB are actually present in these sam ples.

Some evidence of the presence of GB comes from the

fact that m atching features obtained at high tem peratures are system atically better resolved when decreasing

eld than increasing eld as a consequence of a delayed entrance of vortices in the sample but without a ecting their exit. However, in most cases the observed di erence is almost imperceptible thus suggesting that the ubiquitous GB are not relevant. This result is consistent with the highly symmetric dc-magnetization loops observed for all tem peratures studied as shown for example in the left upper inset of Fig.6. In other words, if GB were indeed the responsible for the observed periodic jumps, this periodicity should be absent in the decreasing branch of the loop, in contrast to the general observation. Additionally, in a recent work we have shown that the ac-susceptibility response can be accurately described within the simple Bean critical state model for the perpendicular geometry without invoking the existence of GB. Indeed, in a system dom inated by the GB, currents are constrained to ow along the sam ple's edge and therefore the sam ple's response could be modeled as that produced by a ring-shaped sam ple.²² This particular geom etry will lead to a dom e-like Cole-Cole plot m ore symmetric around $^{0} = 0.5$ than that shown for example in Fig. 3.

We can gain further insight in this particular issue by m easuring the third harm onic susceptibility $_{3}$ (T;H;h). The advantage of m easuring this component lies in the asymmetry of the penetration-exit process which leads to a di erent shape of the minor loops traced out during an ac-cycle for the case of GB and bulk pinning.³³ Fig. 7 shows one of these measurements for the AD 65 sam ple at H = 500 G and h = 0.3 G. A lthough we have also collected $_3$ (T) data in the tem perature range 5 K < T < 7.5 K, at several dc elds (0 G < H < 1 kG) and ac-drives (0.03 G < h < 3 G), for all these conditions the curves are very much alike. In the same qure we have included the tem perature dependence of the third harm onic components $\frac{0}{3}$ (T) and $\frac{00}{3}$ (T) calculated using the Bean model for a disc shaped sample with eld applied perpendicular to the plane of the disk.^{22,34} As we can see, the theoretical curves reproduce qualitatively the main features of the measured third harm onic. In contrast to that, these features cannot be accounted for by using the expression for a ring (sim ilar to that obtained for edge barriers). This behavior becom es m ore evident in the inset of Fig. 7 where a Cole-Cole plot of the third harm onic using the same data shown in the main panel is presented together with the theoretical curve for the critical state in a disk shaped sample within the Bean model scenario. We also included in this gure the curve for a ring rescaled by a factor $_0$ to twith the experimental data and accounting for the expected am plitude dependence in the case of GB (strictly this is not valid but it rescues the basic heart-shaped curve obtained in the case of GB which allows one to make a fast comparison).

In the inset we clearly see that as for the disk geom – etry, the measured curve occupies the quadrants II, III and \mathbb{N} . In contrast to that, in the case of GB dom inating

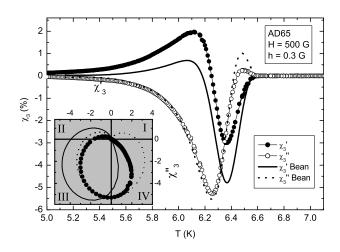


FIG. 7: Main panel: Temperature dependence of the real (led circles) and imaginary (open circles) components of the third harmonic susceptibility for the AD 65 sample at H = 500 G and h = 0:3 G. The theoretical expectations for a disk in a critical state described by the Bean m odel are shown. In the inset the theoretical curve (solid line) and experimental data (led circles) already shown in the main panel are represented in a Cole-Cole plot together with the curve for a ring shaped sample (dotted line).

behavior, the rst quadrant (corresponding to low temperatures) should also be covered. This feature remains for all amplitudes and dc elds studied, thus suggesting that the contribution of G B to the total response is very weak. On the other hand, the observed di erence (mainly in $^{0}_{3}$ (T)) between the Bean prediction and our experimental results, m ight be accounted for by assuming the more realistic case of eld dependent critical current as in the K im model.^{35,36}

An alternative explanation for the observed periodicity in the ux jumps was recently proposed by H ebert et al.¹¹. A coording to these authors, at low temperatures the ux prolecorresponds to a multiterrace critical state composed by steps of constant B and zero critical current connected by abrupt changes in the ux density where the current is higher than that obtained from the average slope of the ux prole^{3,7} In this scenario, the sudden penetration of a new terrace induces the m ovem ent of the internal terraces giving rise to jumps in the magnetization. At very low temperatures the concept of terraced state is lost as a more disordered ux distribution appears. On the other hand since the avalanches are triggered by the local slope rather than the average slope of the ux pro le, this model satisfactorily accounts for the observed increase of the H T region where uxjumps are detected in the patterned samples. However, a complete explanation of this puzzling observation remains elusive at the moment, and clearly further experimental and theoretical studies are needed.

In the nalstage of preparation of this manuscript we learnt about a recent report by Zhukov et al.³⁸ showing several common results with the present work.

IV. CONCLUSION

We have shown that the low tem perature magnetic behavior of Pb Im s is dominated by vortex avalanches regardless the details of the pinning array. A lthough the size of the ux jumps is strongly reduced by introducing a periodic pinning array, the region of the H T plane where ux-jumps occurs is enlarged for patterned sam ples. This draw back can lim it at low tem eratures the applicability of these arrays to reduce the noise in SQUID system s as proposed recently.¹⁰ At low tem peratures and

eds an almost T - and H -independent m agnetization is found. A lthough there is no clear clue to interpret this behavior, it m ight be related with the channeling of vortices by the prede ned dendritic structures. F inally, we have demonstrated that the observed quasi-periodic jum ps are unlikely to be originated in geom etric barriers. Instead, a multiterrace critical state could satisfactorily account for this e ect.

A cknow ledgm ents

W ewould like to thank R.Jonckheere for fabrication of the resist patterns. This work was supported by the Belgian Interuniversity Attraction Poles (IUAP), Research Fund K JJ Leuven GOA/2004/02, the Fund for Scienti c Research Flanders (FWO) and ESF \VORTEX" program.

- ¹ V.V.Chabanenko, A.I.D'yachenko, M.V.Zalutskii, V. F.Rusakov, H.Szymczak, S.Piechota, and A.Nabialek, J.Appl.Phys.88, 5875 (2000).
- ² R.G.M ints and A.L.Rakhm anov, Phys.M od.Phys.53, 551 (1981).
- ³ F.L.Barkov, D.V.Shantsev, T.H.Johansen, P.E.Goa, W.N.Kang, H.J.Kim, E.M.Choi, and S.I.Lee, Phys. Rev.B 67,064513 (2003).
- ⁴ M.Baziljevich, A.V.Bobyl, D.V.Shantsev, E.Altshuler,
- T.H.Johansen, S.I.Lee, Physica C 369 (1-4), 93 (2002). 5 C.A.Duran, P.L.G am mel, R.E.M iller, and D.J.B ishop,
- Phys.Rev.B 52, 75 (1995).
 ⁶ P.Esquinazi, A.Setzer, D.Fuchs, Y.Kopelevich, E.Zeldov, and C.Assmann, Phys.Rev.B 60, 12454 (1999).
- ⁷ T.H.Johansen, M.Baziljevich, D.V.Shantsev, P.E.Goa, Y.M.Galperin, W.N.Kang, H.J.Kim, E.M.Choi, M. S.Kim, S.I.Lee, Supercond. Sci. Tech. 14, 726 (2001).
- ⁸ J. Vanacken, L. Trappeniers, K. Rosseel, I. N. Goncharov,

V.V.Moshchalkov, and Y.Bruynseraede, Physica C 332, 411 (2000).

- ⁹ R.W ordenweber, A.M. Castellanos, P. Selders, Physica C 332 27 (2000).
- ¹⁰ A. Crisan, P. Badica, S. Fujiwara, J. C. Nie, A. Sundaresan, Y. Tanaka, and H. Ihara, Appl. Phys. Lett. 80, 3566 (2002).
- ¹¹ S. Hebert, L. Van Look, L. Weckhuysen, and V. V. Moshchalkov, Phys. Rev. B 67, 224510 (2003).
- ¹² I.A ranson, A.G urevich, and V.V inokur, Phys.Rev.Lett. 87,067003 (2001).
- ¹³ V.V lasko-V lasov, U.W elp, V.M ethushko, G.W. Crabtree, Physica C 341 1281 (2000).
- ¹⁴ A. Terentiev, D. B. W atkins, L. E. D e Long, L. D. Cooley, D. J. Morgan, and J. B. K etterson, Phys. Rev. B 61, R 9249 (2000).
- ¹⁵ S. Raedts, A. V. Silhanek, M. J. Van Bael, and V. V. Moshchalkov, Physica C 404, 298 (2004).
- ¹⁶ M. Yoshida, S. Nakata, T. Ishida, Supercond. Sci. Tech. 14 (12) 1166 (2001).
- ¹⁷ A.V. Silhanek, S. Raedts, M. J. Van Bael, and V.V. Moshchalkov, Eur. Phys. J.B 37, 19 (2004).
- ¹⁸ A.A.Zhukov, E.T.Filby, M.A.Ghanem, P.N.Barlett, P.A.J.de Groot, Physica C 404, 455 (2004).
- ¹⁹ W.A.C.Passos, P.N.Lisboa, W.N.Kang, E.M.Choi, H. J.Kim, S.I.Lee, W.A.Ortiz, IEEE T.Appl. Supercon. 13 3699 (2003); J.Supercond. 15, 479 (2002).
- ²⁰ J. G iapintzakis, R. L. Neim an, and D. M. G insberg, and M. A. Kirk, Phys. Rev. B 50, 16001 (1994). P. Zhang, S. Y. Ding, X. F. Wu, L. Qiu, Z. H. Wang, C. Ren, S. A. A runa, and X. X. Yao, and J. Shi, Phys. Rev. B 62, 5374 (2000).
- ²¹ F.Irie, G.K lipping, K.Luders, T.M atsushita, U.R uppert, M.Takeo, EEE T.M agn. 13, 530 (1977).
- ²² Th.Herzog, H.A.Radovan, P.Ziemann, and E.H.Brandt, Phys.Rev.B 56, 2871 (1997).
- ²³ H.A.Radovan and R.J.Zieve, Phys.Rev.B 68, 224509

(2003).

- 24 Strictly speaking this critical eld corresponds to the eld H $_{\rm c3}$ where superconductivity rst nucleates around the holes of the pinning array.
- ²⁵ M. Daum ling and D. C. Larbalestier, Phys. Rev. B 40, 9350 (1989)
- ²⁶ M.H.Jericho, W.Odoni, and H.R.Ott, Phys. Rev. B 31, 3124 (1985).
- ²⁷ N.Novotny, P.M. Meincke, and J.H.P.W atson, Phys. Rev.Lett. 28, 901 (1972).
- ²⁸ R.G. M ints and E.H. Brandt, Phys. Rev. B 54, 12421 (1996).
- ²⁹ I. A. Rudnev, S. V. Antonenko, D. V. Shantsev, T. H. Johansen, and A. E. Primenko, Cryogenics 43, 663 (2003).
- ³⁰ A.Gerber, J.N.Li, Z.Tarnawski, J.J.M.Franse, and A. A.Menovsky, Phys. Rev. B 47, 6047 (1993).
- ³¹ A.V. Silhanek, L.Van Look, S.Raedts, R.Jonckheere, and V.V. Moshchalkov, Phys. Rev. B 68, 214504 (2003).
- ³² M. Pannetier, R. J. W ijngaarden, I. Fl an, J. Rector, B. Dam, R. Griessen, P. Lahl, and R. W ordenweber, Phys. Rev. B 67, 212501 (2003).
- ³³ C.J.van der Beek, M.V.Indenbom, G.D'Anna, and W. Benoit, Physica C 258, 105 (1996).
- ³⁴ T. Ishida and R. B. Goldfarb, Phys. Rev. B 41, 8937 (1990).
- ³⁵ O.O zoguland A.A ydinuraz, Supercond.Sci.Technol.14, 184 (2001).
- ³⁶ G. M. Maksim ova, D. Yu. Vodolazov, I. L. Maksim ov, Physica C 356, 67 (2001).
- ³⁷ L.D.Cooley and A.M.Grishin, Phys.Rev.Lett. 74, 2788 (1995); V.V.Moshchalkov, M.Baert, V.V.Metlushko, E. Rossel, M.J.Van Bael, K.Temst, and Y.Bruynseraede, Phys.Rev.B 57, 3615 (1998).
- ³⁸ A A Zhukov, E J Filby, P.A.J. de G root, V V M etlushko, and B Ilic, Physica C 404, 166 (2004).